Organic field-effect transistor sensors: a tutorial review

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The functioning principles of electronic sensors based on organic semiconductor field-effect transistors (OFETs) are presented. The focus is on biological sensors but also chemical ones are reviewed to address general features. The field-induced electronic transport and the chemical and biological interactions for the sensing, each occurring at the relevant functional interface, are separately introduced. Once these key learning points have been acquired, the combined picture for the FET electronic sensing is proposed. The perspective use of such devices in point-of-care is introduced, after some basics on analytical biosensing systems are provided as well. This tutorial review includes also a necessary overview of the OFET sensing structures, but the focus will be on electronic rather than electrochemical detection. The differences among structures are highlighted along with the implications on the performance level in terms of key analytical figure of merits such as: repeatability, sensitivity and selectivity.

Key learning points: organic field-effect transistors (OFETs); CHEMFETs, FET biosensors; bio-recognition at OFET functional interfaces; sensors analytical figures of merit.

Introduction

Electronic sensors are conceived to function as core elements in miniaturized, possibly fully integrated, systems capable to detect a substance and deliver an already processed digital response. Such systems, also addressed as smart sensors, feature the integration of a microprocessor (embedded intelligence) along with the chosen sensor technology. Smart sensors are foreseen as capable to provide not just a customized output but also a significantly improved level of performance. The aim is to realize systems that are endowed with capabilities such as self-calibration, self-healing and production of compensated measurements. The latter meaning the ability to produce an output signal that is already corrected for variables such as temperature, analyte concentration, interferentes and base-line drift, just to quote the most relevant. All this would make smart systems performances desirably solid and reliable.

Sensitive, selective, miniaturized, light-weight, low-power, biosensing systems should be capable to provide the information to the user wherever and whenever it is needed. In a more visionary scenario, the system is even expected to furnish the right information on what it is required to make sound decisions. A smart system for the detection of biological molecule of interest in clinical analysis (nucleic acids, metabolites, proteins, pathogens, human cells and drugs), would be ideal for application in what is addressed as point-of-care (POC) testing. Such a novel approach foresees clinical tests to be performed at or near the site of patient care,
namely the medical doctor office or even the patient house, allowing for timely initiation of appropriate therapy and/or facilitating the linkages to care and referral. POC tests should be in fact simple enough to be used at the primary care level and in remote settings with no laboratory infrastructure. POC has therefore the potential to improve the management of diseases as well as of regular medical check-up testing.

This tutorial review aims at providing the necessary knowledge on the Organic field-effect transistor (OFET) sensors highlighting the features that would make them ideal for POC applications. As the electrochemical OFET sensing configurations have been recently extensively reviewed here the focus will be on electrolyte and back-gated OFETs biosensors.

In general OFET sensors use \( \pi \)-conjugated organic semiconductors (OSCs) as electronic materials and are endowed with biological recognition capabilities by proper functionalization or integration of bio-systems such as DNA strains, antibodies, enzymes and capturing proteins in general. The advantages over other sensing technologies such as electrochemical or optical based ones is the capability of delivering a response that is label-free using a simple electronic read-out setup that can be easily miniaturized also employing printed circuit technologies. Before going into the functional details of these devices it is worth mentioning that OFETs are developed in the framework of the organic or plastic electronic technology that is a relatively new field in which the device structures are based on organic materials being dielectric, conductive or semiconducting organic (macro)molecules. The revolutionary concept that is now turning into real prototypes, involves the realization of functioning electronic and opto-electronic devices (light-emitting diodes, photovoltaic cells, OFETs) and circuits by printing features on plastic or paper substrates using dielectric, conducting, insulating and semiconducting inks. Plastic electronic systems are produced at very low-cost using printing equipment instead of ultraclean high-tech fabrication facilities. The emerging field of organic electronics is therefore motivated by the possibility of mass-producing cheap and sustainable electronic devices and sensors. In Fig. 1 an example of inkjet printed, transparent OFETs on a flexible substrate, is featured.

Fig. 1 Picture of transparent and flexible OFETs. Reprinted from reference 8, Copyright© 2011 Elsevier B.V, reproduced with permission from Elsevier.

Typical materials for OSC include polymers such as poly(3-hexylthiophene) (P3HT) and alkyl-substituted triphenylamine polymers (PTAA) but also oligomers such as pentacene and its soluble derivatives as well as many other organic materials capable of providing OFET devices with mobility in excess of 1 cm\(^2\)/Vs. More recently, natural and nature-inspired materials, such as indigoid dyes have been used as active layer in OFETs that perform at the state-of-the-art level. Interestingly, these devices can be fabricated entirely from inexpensive and natural, biodegradable materials. The driving force towards the use of OFET as biosensors is to combine the electronic output signal and the high sensing performance level with low-cost fabrication to develop disposable electronic sensing systems that would turn ideal for POC testing.

This tutorial review starts with an overview on what a biosensor is and the analytical figures of merits that need to be assessed are introduced in an operative manner. The importance of the label-free approach is highlighted too. This part is important as the analytical assessment is very seldom part of a study dealing with...
organic electronic sensors. OFETs are then introduced and their operation as chemical sensors is briefly presented. These are performing devices that, however, lack selectivity. To understand how to implement selectivity features, some OFET relevant approaches to bio-functionalization are presented. The last session deals with the description of OFET biosensor configurations with particular attention to those involving electronic transduction. As anticipated, electrochemical OFET biosensors are not extensively discussed here.

**An overview to biosensing and clinical testing**

According to the International Union of Pure and Applied Chemistry (IUPAC) a biosensor is a device that uses specific biochemical reactions mediated by isolated enzymes, immuno-systems, tissues, organelles or whole cells to detect chemical compounds usually by electrical, thermal or optical signals. In other words, a biosensor is an analytical device involving biological recognition elements whose interaction with an analyte is turned into a measurable signal by a transducer. A block diagram of a biosensor is reported in Fig. 2.

![Fig. 2 Schematic representation of the main components of a biosensor.](image)

Since the development of the first enzymatic biosensor by L.C. Clark and C. Lyons in 1962, there has been worldwide an intense research activity on biosensors. Particularly, the success of glucometers, used to monitor the glucose blood concentration in diabetics, as well as the commercialization of lateral flow assays such as pregnancy test, have led clinical diagnostic to be the most significant area for the application of biosensors particularly as POC systems. It is currently recognized that early diagnosis are essential prerequisites for prevention and treatment of diseases and can contribute to reduce the medical costs of healthcare services. The availability of sensitive, robust, affordable and rapid diagnostic tools, to be used outside of conventional clinical laboratories, can drastically contribute to reduce the number of deceases for infection diseases such as HIV, tuberculosis and diarrheal infections in developing countries. It is worth to mention that biosensors can be used for detecting a wide range of clinically relevant targets present in biological fluids including blood, saliva, urine and even tears by just coupling the specific recognition elements to the transducer. For instance, enzymatic biosensors, that use enzymes for the recognition process, are mainly employed for the detection of metabolites such as glucose, lactate, urea, ammonia, creatinine, cholesterol and uric acid. These compounds are important diagnostic indicators of diseases such as diabetes, respiratory insufficiencies, kidney injury, hypertension, hyperthyroidism, ischemia and leukemia. On the other hand, biosensors based on affinity binding interaction (i.e. immuno-sensors such as the well-known pregnancy test) are principally used for screening proteins (including enzyme or antibodies), hormones and even whole cells that are biomarkers for cancer, cardiovascular, inflammatory and infectious diseases. Furthermore, geno-sensors, that employ nucleic acids as recognition elements, allow detecting the presence of DNA or RNA in clinical samples in order to identify genomic or genetic based pathologies. These biosensors are also widely employed to reveal the presence of infections caused by virus, bacteria or fungi.

Biosensing instruments designed for clinical applications can be divided into two
types: high-throughput, sophisticated equipment mainly operated by skilled personnel for diagnostic or R&D purposes in clinical or research laboratories, and user-friendly, portable POC devices designed to be used directly by non-trained persons at the place where the monitoring is needed (i.e. doctor’s office or patient’s home).

Implantable and wearable biosensors can be considered an alternative to the latter approach for monitoring physiological parameters such as blood oxygen levels or to continuously reveal analyte concentrations in biological fluids, in a non-invasive manner, in situations where personalized medicine is needed (diabetes, infertility, patients treated with anticoagulant drugs). OFET electronic sensors could be ideal for POC systems and interesting would be the use of the recently introduced biodegradable or even sorbable systems for implantable devices.

As to biosensors detection is concerned, two different signal transduction principles have been reported so far: *label needing* technologies in which the analyte or the recognition element are conjugated with an optical or electroactive probe that is revealed by the transducer, and *label free* methods where a change in a physical variable, produced during the recognition process, is directly measured. Electrochemical and optical label needing methods have been widely employed so far in the development of biosensors. As to electrochemical detection is concerned, it mostly involves enzymatic amperometric biosensors. In the simplest configuration, the glucose oxidase enzyme is immobilized underneath a semi-permeable membrane at the surface of a working electrode. The enzyme catalyses the reaction of glucose with oxygen forming gluconolactone and hydrogen peroxide. The electrode membrane is permeable to the latter compound, which is oxidized at the working electrode. This oxidation produces a current that is proportional to the glucose concentration of the sample, allowing the monitoring of glucose concentration in blood. While electrochemical sensors can be easily adapted in portable and miniaturized devices at low cost, their full integration into a circuit (also as arrays) is not yet being reliably achieved. This is mostly connected to their need of a reference electrode whose integration into a circuit is still an open issue.

Label free technologies, thanks to their simple detection scheme (only one capture molecule is immobilized at the transducer detecting interface), are widely employed to monitor bio-affinity interactions and evaluate binding kinetic parameters in real time. Optical instruments based on Surface Plasmon Resonance (SPR) were the first to be proposed for biosensors development. For many years these devices have represented the gold standard in drug discovery and life science research. However, the complexity of the detecting apparatus as well as the high fabrication costs (adequate temperature control, accurate micro-fabrication processes and extraordinary quality optics needed), have driven researchers to investigate more simple and inexpensive techniques. Hence, technologies such as resonant mirror, diffraction gratings, interferometry, mechanical Quartz Crystal Microbalance, surface acoustic wave sensors, electrochemical impedance spectroscopy as well as electrical transduction devices such as ion sensitive FETs (*vide infra*), were developed. Although several of these *label free* biosensors have shown good sensitivity their integration in compact POC devices it is still far from seeing the market horizon. An organic electronic biosensor, that does not need a reference electrode to be reliably operated, can represent a challenging opportunity for integration into a POC.
Analytical biosensors: the basics on performance figures of merit

Validation of an analytical method is an essential step to assess its capability to provide reliable qualitative or quantitative data. This applies also (and more compellingly) to a novel technology such as electronic biosensing is. The analytical figures of merit that needs to be assessed are selectivity, calibration range and linearity (along with sensitivity and limit of detection), precision, accuracy, limits of detection and quantification. Although several efforts have been made to internationally standardize the guidelines for bio-analytical method validations, there is still the need to clarify the meaning and interpretation of crucial aspects of sensing assays validation. These concepts are operatively introduced below.

**Selectivity:** In biosensors development it is very important to be sure that a given signal (response) is due only to the presence of the target analyte/analytes in an investigated sample. Selectivity is therefore the capability of the bio-analytical method to discriminate the analyte from interfering components such as other analytes or matrix components (metabolites, impurities, degradation products). According to IUPAC the selectivity of a method refers to the extent to which it can determine particular analytes under given conditions in mixtures or matrices, simple or complex, without interferences from other components. Specificity instead, is addressed as the ultimate of selectivity, e.g. 100% of selectivity. Being the latter condition difficult to achieve by definition, the term selectivity should be preferred to specificity. Among the different methods for biosensor selectivity determination, two are generally recommended. Operatively, the first one consists in measuring the biosensor response against interfering substance(s). In that, a calibration curve for each interfering substance is plotted and compared to the analyte calibration curve, every curve being measured under identical operating conditions. Selectivity is then expressed as the percentage of variation of the biosensor response. It is important to point out that, while a large number of bio-chemical (protein-protein, antibody-antigen, nucleic acid hybridization etc.) interactions can be ranked as selective, very seldom chemical interactions, involving weak interaction forces, can be addressed as such. This is the reason why, to endow a sensor with selectivity capabilities biological systems should be preferably implemented. As one of the few exceptions, quite selective detecting capability can be reached either by using organometallic complex chemistry to sense ions or by exploiting catalytic interactions. In any case a selective interaction should never be taken for granted but always duly demonstrated by one of the previously described procedures.

**Calibration curve:** The biosensor calibration is performed by evaluating the relationship existing, within a specified range, between the sensor response and the concentration of the analyte standard solutions. Five or more analyte standard solutions, covering at least two orders of magnitude of concentrations, are necessary for the calibration. When possible, physiological experimental conditions (in terms of analyte molarity, pH and ionic strength of the medium, etc.) should be used. The calibration standards should be evenly spaced over the concentration range of interest and they should be run at least in duplicate (preferably triplicate or more),
and should be measured in a random order. The evaluation of responses from the negative control/blank (solution without analyte) is also required. The calibration curve is to be obtained by plotting the response (R) for the analyte standard solutions (corrected for the background) versus the analyte concentrations or its logarithm. The use of normalized responses (e.g. \( \Delta R/R_0 \), where \( \Delta R = R_{\text{analyte}} - R_0 \) and \( R_0 \) is the blank response) is recommended. The linearity of the calibration curve is determined by an adequate regression analysis of the data.

The best operating conditions should be selected by comparing the results obtained with different calibration curves measured on the same or on different devices. In the former case the response repeatability and in the latter the reproducibility will be assessed. At each concentration level, the precision should be estimated by the relative standard deviation calculated as: \( \text{RSD} \% = (\text{SD}/R_{\text{mean}}) \times 100 \) where SD is the standard deviation and \( R_{\text{mean}} \) is the biosensors relative response averaged over at least three replicates as \( \Delta R/R_0 \). The pertinent regression parameters should be calculated for each experiment and, optionally, they can be statistically analyzed to determine intra- and inter-device variability.

**LOD, LOQ and sensitivity:** The Limit of Detection (LOD) is defined as the lowest amount of an analyte in a sample which can be detected but not necessarily quantified as an exact value. The LOD is expressed as a concentration corresponding to the smallest signal that can be detected with reasonable certainty for a given analytical procedure. The most common approach foresees the evaluation of a response to the analyte that is reliably above the signal coming from the blank solution (baseline). Operatively, the first step is to measure the responses of at least ten independently prepared blank samples, evaluating the corresponding mean \( (B_{\text{mean}}) \) and SD \( (\sigma_B) \) values. The LOD can be then calculated as the concentration corresponding to a response that is \( B_{\text{mean}} \pm k \sigma_B \), whereby \( k \) is a numerical factor chosen according to the level of confidence required.\(^{15}\) IUPAC recommends a value of \( k=3 \) as the probability of a blank signal being 3-fold higher than the \( B_{\text{mean}} \) (i.e. a false positive) is less than 1%. The LOD may not be confused with the sensitivity of the method. The latter is the capability to discriminate small differences in concentration or mass of the test analyte and is equal to the slope of the calibration curve. The limit of quantification (LOQ) is defined as the lowest concentration of an analyte in a sample that can be quantitatively determined with a given precision and accuracy. Operatively, the LOQ is estimated by taking \( k=10 \) in the LOD definition.

The quantification range can be defined as the range of concentrations, including the higher and lower limit of quantifications, that can be reliably and reproducibly quantified with accuracy and precision through the use of a concentration-response relationship. Finally, it has to be pointed out that the LOD and LOQ values, in the case of biosensors based on bio-recognition processes, directly correlate with the relevant dissociation constant. Indeed, the LOD is lower for analytes with lower dissociation constants and higher for analytes with higher dissociation constant (i.e. with lower binding affinities). Moreover, the biosensor response will be always negligible for concentration much lower than the dissociation constant. In Fig. \( 3 \) a calibration curve along with the LOD and the LOQ are reported for a streptavidin OFET biosensor. The LOD is 10 nM while the LOQ is 18 nM while the streptavidin-biotin dissociation constant is in the fM range.
Fig. 3 A typical calibration curve showing the response as a fractional current increment of an Electrolyte Gated OFET biosensor to streptavidin (*vide infra*). The LOD and the LOQ levels are graphically represented on the calibration curve.

## Organic Field-Effect Transistors

Before entering into the details of the OFETs sensors an introduction to the basic functioning principles of an organic field-effect transistor is necessary. First introduced in the 1980s, OFETs have reached now performance levels comparable to that of their polycrystalline inorganic homolog and a number of p-type and n-type organic semiconducting materials with different chemical and physical properties exhibiting field-effect mobilities higher than 1 cm²/Vs can be found.⁹

A typical OFET structure is shown in Fig. 4a, while Fig. 4b shows the device exposed to a gaseous atmosphere.

![Fig. 4 Scheme of a typical OFET device structure before (a) and after exposure to an analyte (b)](image)

In its simplest form, an OFET comprises a gate contact that is defined on the substrate which could be rigid (a silicon wafer) or flexible (plastic or even paper). Resorbable materials¹⁷ have also been recently introduced demonstrating that the whole device can be dissolved in few days. Implantable POC applications with such a technology would allow avoiding the step of system removal after use. The gate electrode is in contact with a dielectric that is interfaced to the OSC film. The gate dielectric should have a high capacitance either because it holds a high dielectric constant $k$, or because it is a thin-film as it will be discussed later.

The OSC can be made of oligomers or polymers that are deposited as films (a few tens of nanometers thick at most) by solution casting, spin coating or sublimation. Other deposition methods are also used, including printing techniques.⁸ Solution processed OSCs are generally polycrystalline films composed of contiguous grains with linear dimensions of a few hundred nanometers.¹⁸ Source and drain contacts to the OSC can be easily defined either by thermal evaporation through a screen-mask or again by printing. Gold is the most convenient contact metal because its work function is the closest to that of most p-type organic materials. For p-type OSC the device is operated by independently negatively biasing the drain (D) and the gate (G) contacts applying the $V_{DS}$ and $V_{GS}$ potentials with respect to the grounded source (S). This is called *common source configuration*. Eventually, a channel of positive charges, whose geometrical length ($L$) is the distance between the source and the drain pads, is formed between these contacts. The channel width ($W$) is the geometrical width of the pad.

A definitive model for OFET transport mechanisms and operation is still to be produced, nonetheless several reviews can be found that very well describe the present understanding.¹⁹ Here only the most relevant aspects will be summarized in a rather phenomenological fashion. The metallic source and drain contacts are electrically connected to an OSC (p-type in this case) and are meant to inject and collected positive charges (see Fig. 4). Alike most thin-film transistors, also OFETs operate in the so called *accumulation mode* (*vide infra*) and a highly resistive OSC resulting in a low $I_{DS}$ current in the off state ($V_{GS} = 0$) is necessary. The $I_{DS}$ current flowing in the *on-state* ($V_{GS} < 0$) must be, instead, as high as possible. The switching
between the two transport regimes is achieved as the gate-contact and the OSC channel are capacitively coupled through the dielectric layer, allowing positive charges to be accumulated and confined in the OSC at its interface with the dielectric layer. In that, $V_{GS}$ controls the accumulation of charges at this interface while, under an imposed bias $V_{DS}$, the $I_{DS}$ current flows between the source and drain electrodes. In other words, the field generated by the negative $V_{GS}$ bias applied across the dielectric layer, leads to a band-bending in the OSC as depicted in Fig. 5.

**Fig. 5** Band diagram of Metal-Insulator-(p-type)Semiconductor (MIS) structure at a) zero gate ($V_{GS} = 0$), b) accumulation ($V_{GS} < 0$) and c) depletion ($V_{GS} > 0$) modes

In Fig. 5a the band structures of the metal gate, the insulator (gate dielectric) and the OSC are depicted when no gate bias is imposed. The few positive charges in the OSC are due to the presence of p-type dopants whose control, at the ultra-low trace level, is very difficult particularly in not fully ordered materials. Fig. 5b shows what happens at the interface when a negative $V_{GS}$ is imposed. This generates a potential well that allows positive charges to be confined and accumulated at the OSC-dielectric interface forming a conductive channel (between source and drain contacts) running through an ideal path perpendicular to the drawing plane. Due to this confinement the field-induced transport is two-dimensional (2D) that is to say, independent of the OSC thickness, provided a continuous OSC thin layer is deposited. Conversely the transport occurring at $V_{GS} = 0$ is tree-dimensional (3D) as it involves the charges present in whole p-type OSC film. The presence of these charges (that must be orders of magnitude lower that those induced by the gate field) is due to doping processes connected with the presence of impurities or structural defects difficult to be controlled at the trace level. The field generated by the $V_{DS}$ bias allows the charges present in the OSC potential well (OFET channel) to migrate in a direction perpendicular to Fig. 5 plane. Indeed, the larger the negative gate bias the larger the accumulated charge density, the more intense the $I_{DS}$ on-current is; this being the reason way this is addressed as accumulation mode operation. For an n-type OSC negative charges are accumulated at the interface by applying positive $V_{GS}$ bias and current flaws for positive $V_{DS}$. To make sure that the transport in the channel is two-dimensional, it is necessary that the field generated by $V_{GS}$ (normal to the channel plane) is always much larger than the one generated by the $V_{DS}$ bias along the channel (gradual channel approximation). Again for a p-type OSC, if a positive gate voltage is applied, the field causes a bending the semiconductor bands (or more correctly the molecular HOMO and LUMO levels) edges upwards, causing the positive charges to be accelerated towards the bulk of the OSC (Fig. 5c). The OFET channel region is then depleted and the $I_{DS}$ current flow reduced (depletion mode).

The charge transport in the polycrystalline OSC involves carriers to migrate through the channel region by hopping between the localized states present inside the band gap (energy gap between the HOMO and LUMO levels) of the OSC. These films are in fact systems comprising a narrow delocalized band associated with a high concentration of localized lower-energy electronic states that are located in the band gap and act as low mobility trap states. The trapping states are also most probably originated by impurities and/or structural defects located in the crystalline grain or at grain boundaries. Localized states in the OSC gap act as trapping or doping states depending on how stable a radical cation or anion is or equivalently
how energetically close the localized state is to a delocalized molecular levels. Indeed, traps are deep (far from the delocalized levels edges), low mobility states. The energy barrier between the grains is proportional to the surface density of charge traps at the grain boundaries themselves. In polycrystalline OSC material transport takes place within a grain and across the boundary and, generally, the slower (rate determining step) process is the tunneling across the grain boundaries that causes the mobility to be limited by thermionic emission over the potential barrier at the grain boundaries.

As $V_{GS}$ is applied the conditions for charge accumulation are set but the $I_{DS}$ on-current flow does not start until a threshold gate voltage ($V_T$) is reached. This marks the gate bias needed to turn the transistor on. In thin-film transistors $V_T$ is in fact equal to $Q_{deep}/C_i$ where $Q_{deep}$ is the density of charges that, once injected in the channel, are trapped while $C_i$ is the dielectric capacitance per unit area. So $V_T$ is the gate voltage necessary to induce the charges. $Q_{deep}$, required to completely populate the deep trap energy levels. Once all traps are filled the further injected charges can migrate along the delocalized molecular orbital with a given mobility, through the channel under the imposed $V_{DS}$ bias.

Typical current–voltage, I–V, curves for a P3HT p-channel OFET are shown in Fig. 6a.

As for all FET-based devices the set of $I_{DS}$ currents is measured as a function of $V_{DS}$ and each individual curve at a different, fixed $V_{GS}$ bias. The curves are characterized by a linear region at $V_{DS} \ll (V_{GS} - V_T)$ and a saturation region at $V_{DS} > (V_{GS} - V_T)$. At low drain-source voltages the $I_{DS}$ current follows Ohm’s law being proportional to $V_{DS}$ at a fixed $V_{GS}$ (linear regime). In this regime the gradual channel approximation holds as the field generated by the gate potential is much larger the one generated by $V_{DS}$. As the drain-source voltage becomes more negative a point is reached where the positive charges accumulated in the channel region are depleted at the drain contact region. At this ends the field along the channel (generated by $V_{DS}$) becomes too high compared to the gate one and the charge two dimensional confinement is lost. The presence of this charge depleted region generates a pinch-off of the channel and the current flow is limited to a constant value $I_{DS}^{sat}$ (saturation regime). These features are well reproduced by the MOSFETs analytical expressions, generally used also to describe the OFET I-V curves. The equations are reported in the following:

$$I_{DS} = \frac{W}{L} C_i \mu \cdot (V_{GS} - V_T) V_{DS} \quad V_{DS} \ll (V_{GS} - V_T); \text{ linear region} \quad (1)$$

Here $W$ and $L$ are the already introduced channel width and length, respectively; $\mu$ is the field-effect mobility (cm$^2$/Vs) measuring how fast charges migrate under the imposed electric field. In the saturated region the following equation holds:

$$I_{DS}^{sat} = \frac{W}{2L} C_i \mu \cdot (V_{GS} - V_T)^2 \quad V_{DS} \gg (V_{GS} - V_T); \text{ saturation regime} \quad (2)$$
Fig. 6b shows the square root of the $I_{DS}^{sat}$ vs. $V_{GS}$ transfer characteristic at constant $V_{DS}$ taken in the saturation region. The field-effect mobility, which is generally not constant in OFET devices, can be estimated from this curve. Operatively, equation 2 can in fact be written as follows:

$$\sqrt{I_{DS}} = \sqrt{\frac{W}{2L}} C_i \mu \cdot V_{GS} - \sqrt{\frac{W}{2L}} C_i \mu \cdot V_T = A \cdot V_{GS} - B$$

(3)

the value of $\mu$ (from the saturated region) and $V_T$ can be graphically extracted from the linear fit to equation 3, reported as an example in Fig.6b with $A$ and $B$ being the slope and the x-axis intercept:

$$\mu = \frac{2L}{WC} A^2$$

(4)

$$V_T = -\frac{B}{A}$$

(5)

Typical values of $\mu$ for OFETs are in the $10^{-2} - 10^{-1}$ cm$^2$/Vs range, but values as high as $1 - 10$ cm$^2$/Vs can be easily measured. Another figure of merit in an OFET is the on/off ratio, defined as the ratio between of the $I_{DS}$ current values in the on and off state. This is indicative of switching performance of the device between the already introduced two distinct conduction regimes (2D and 3D) taking place in an OFET device.

As it is clear already from the basic description of the device electronic transport properties provided, OFETs are interfacial devices and the interplay between the dielectric and the OSC surfaces is complex and not yet completely understood. Nonetheless it is clearly received that the dielectric layer interfacial properties influence carrier transport and mobility in different ways. Specifically, the chemical and surface properties affect the morphology of the OSC and the orientation of small molecules or polymer segments. These impact on the transport properties that are strongly related to the molecules’ orientation as higher mobility hopping conduction is determined by the length of the $\pi$-delocalization. Moreover the semiconductor/dielectric interface roughness can modulate the mobility of charge carriers. This is the interface that will act as the key relevant one in OFET sensing processes.

**OFET chemical sensors**

The use of an OFET for sensing purposes, in its simplest configuration, involves the direct exposure of the OSC to the atmosphere to be analyzed; in this case, the OSC acts both as the electronic transport material and as the sensing layer (Fig. 4b). The idea behind this approach is as simple as this: as an OFET is capable to generate a current amplification (indicated by the on/off ratio), wouldn’t it be possible, once the OFET it is exposed to an analyte, to achieve also a sensing response magnification? With this in mind the interaction of an analyte with an OFET was investigated by
studying the changes induced in the transport properties upon exposure of the OSC to a target molecule. Operatively, the device I-V transfer characteristics (Fig. 6b) are measured in an inert atmosphere (N₂, pure water or buffer solution depending on the assay) and in the presence of the analyte; the changes of all the device parameters, (μ, Vₜₐₜ, Iₜₐₜ and the on/off ratio) are computed and correlated to the analyte concentration. Before entering into the details of the OFET sensor functioning it is important to anticipate that the OFET detection is label-free and it is also highly repeatable as demonstrated by several groups. It has been also demonstrated that it is sensitive and, upon proper functionalization with biological receptors, can be also selective.

OFET were first proposed as chemical sensors in the late eighties with one contribution and one review published somehow later. After some years from these few earlier reports, OFET sensors were proposed as multi-parametric sensor exploiting the possibility offered by a FET device of measuring simultaneously and at room temperature, the variation of four electrical parameters. In this approach, pioneered in 2000, the field-effect mobility, the on/off current ratio, as well as the threshold voltage and the bulk conductivity of the organic film, constitute the four output parameter used to characterize an OFET sensor response to a given gaseous analyte. The bulk (3D) conductivity is typical of the OSC used as active layer and could be measured in an equivalent resistor sensors, while the others parameters are characteristics of the 2D FET transport and can be easily extracted from the I-V transfer characteristics as exemplified by equations (4) and (5). Compared to the response of a homolog resistor the OFET provides other three parameters that can be used as an analyte finger-print. It is to point out however, that the required selectivity, allowing in principle to identify a species, is possible only if the OFET is endowed with recognition capability furnished typically only by a biological recognition element.

Besides the multi-parametric out-put, another advantage of the OFET response is the enhanced sensitivity. In Fig. 7a the analytical sensitivity (taken as the slope of the calibration curve) measured for an alkoxyphenilenene-thiophene OFET exposed to citronellol vapor, is plotted as function of the device gate voltage.

Fig. 7 a) OFET sensitivity dependence on the gate voltage. Sensitivity values are determined from the slopes of the calibration curves (ΔI vs. analyte concentration) of OFET device exposed to β-citronellol vapors at different gate biases, b) Current change (ΔI) at -50V fixed VGS and VDS bias of OFET devices upon exposure to various concentrations of β-citronellol for different OSC film thicknesses. The data points are average values over three replicates.

As it is evident the device sensitivity increases by three orders of magnitude when the applied gate voltage drives the OFET from the off to the on regime. In Fig. 7b the calibration curves for the same device (exposed to citronellol at fixed VGS and VDS bias) are reported for different OSC thicknesses. Although the film thickness is changed by one order of magnitude going from 95 nm to 950 nm, the device response is not significantly different at each measured concentration. This means that the OFET sensor response is indeed independent of the OSC thickness that is to say it is 2D in nature, very much like the FET on-transport is. Both this experiments concur to demonstrate that there is a correlation between the amplified on-current flowing in the OFET channel and the enhanced sensing response evidencing how the FET amplified sensitivity can allows such type of electronic devices to outperform a resistor bearing the same OSC. Last but not least a further
The sensing mechanism of OFET sensors that uses the OSC also as active layer upon exposure to a gaseous analyte (Fig. 4a) can be described starting from the charge distribution at the semiconductor/dielectric interface region. Depending on the OSC properties and morphology, the analyte can cause changes in the threshold voltage and in mobility due to charge trapping/detrapping and increase/decrease of the potential barrier between continuous grains. As already anticipated, these effects result in a change of the drain source on-current and the 2D conductivity. Moreover, OSCs are amenable to not covalent π-interactions involving ionic bonds, hydrogen bonds and van der Waals forces. The analyte molecules can be adsorbed on the surface of the grains, trapped in the free volume of the amorphous grain boundaries and even percolate through the voids between grains reaching the interface between the OSC with the gate dielectric or with the electrodes. Parameters such as the nature of the analyte (e.g. molecular size, dipole moment, electron affinity) and size of the grain boundaries can affect the response of the sensor. To overcome issues such as sensitivity and cross-selectivity, modification of the semiconductor polymer’s side chains with functional groups or the addition of layers with molecular systems exhibiting some degree of affinity with the analyte, can lead to increase of the binding affinity between the sensitive layer and the gas molecule. This strategy proved successful to reliably detect volatile organic compounds (VOCs) such as alcohols, ketones. Gases such as NH₃, NOₓ involving transfer reactions, also received considerable attention for their detection in environmental monitoring, detection of explosives and disease diagnosis through breath analysis. Different active layers such as substituted thiophene-based polymers and oligomers, pentacene, metallophthalocyanines (MPCs) and metalloporphyrins (MPs) have been used in OFETs for nitro-based explosives, ammonia nitric oxides and peroxides detection. Here the mechanism is such that the analyte induces a positive or a negative V_T shift, depending on the redox properties of the analyte. This can be explained by considering that V_T is sensitive to the charges injected in or withdrawn from the OSC. The electron rich conjugated system, typical of OSCs, makes them sensitive to strong oxidants, such as NO, hydrogen peroxide and nitroaromatic compounds, acting as electron acceptors that trap charges or dope the OSC layer. In this case the increase of I_DS and the positive shifts in V_T, have been observed in p-type materials. Different mechanisms have been proposed involving traps of negative charges due to analyte reduction at the OSC/dielectric interface or accumulation of more holes due to oxidation of the semiconductor. Opposite behaviour is seen when a p-type OSC based OFET is exposed to a reducing agent such as NH₃. The analyte acts as electron donor system causing a decrease in
the $I_{DS}$ current and negative shifts in the threshold voltage. Generally, amines donate electrons from the sp$^3$ hybridized nitrogen atom to the conductive polymer cation.$^{39}$ The positive charges density is reduced in the OSC along with on-current and $V_T$.\textsuperscript{35}

Although mostly chemical sensors have the configuration of Fig. 4b, also few biosensors have been proposed where the OSC acts both as electronic and sensing layer. In this case the bio-recognition element is uniformly distributed in the whole bulk of the OSC.\textsuperscript{40} This approach, although not the most efficient one as it involves a bio-interaction with the bulk while it is the interface that matters, has produced some interesting results in configurations that will be addressed later on in the text.

The discussion of inorganic FET chemical sensors is beyond the scope of this review, but it is relevant to recall few important features, to understand gate modulated OFET biosensors. FETs sensors, first proposed more than forty years ago,\textsuperscript{41} envisaged a silicon Metal-oxide-semiconductor FET (MOSFET) device endowed with a sensing metallic or conducting polymer gating layer. The interaction in this configuration occurs between the analyte and the gate contact eventually leading to a modification of its electrochemical potential. This is mirrored by a $V_T$ shift of the MOSFETs as in this kind of FETs, the threshold voltage is linearly correlated to the gate metal work function (or, equivalently, its electrochemical potential). Hydrogen detection, through the catalytic interaction with a palladium gate, was successfully achieved at very low concentrations. Also worth to mention are the Ion Selective (IS) FET electrodes detecting clinically relevant ionic species by means of a selective membrane gate coating.\textsuperscript{42} These are chemical sensors based on the electrochemical interaction of the analyte with the gating layer. The main draw-back of ISFET-like sensors is the need for a reference electrode to control the potential that makes them less prone for use in array-type smart sensing system.\textsuperscript{12}

In general, the detection of concentrations as low as part-per-billions (but most commonly part-per-millions) can be achieved by using OFET for gas and vapour sensors. Besides, the ability of OFET sensors to combine multi-parametric analysis and signal amplification has been also demonstrated. However, the real limitation of the OFET detection performed by using an OSC both as electronic and sensing layer is the very low degree of selectivity.

**Bio-recognition events at functionalized OFET interfaces**

To endow a sensor with selectivity capabilities it is necessary to implement molecules capable of strong interactions with a target analyte. Very often such systems are addressed as receptors. However, rigorously speaking a receptor is a protein located on the cell surface or inside the cell that, upon binding of a ligand (e.g. hormone or a neurotransmitter) induces a cellular response. Systems endowed, in a more general sense, of selectivity capabilities should be addressed as recognition elements or capturing molecules. They can have very different chemical nature, ranging from simple inorganic complexes to bio-macromolecules such as nucleic acids and proteins (indeed including also true receptors). A prerequisite for a system to be selective is to hold a very precise three-dimensional structure particularly as to the binding sites where molecular recognition takes place, is concerned. Ideally, only the target molecule (ligand or analyte) should fit the stereochernistry of the recognition site. In addition, the involved molecular interactions should be strong enough to form a complex with a low dissociation constant required to achieve low LOD and LOQ. The combination of a stringent
binding site stereochemistry and strong interactions can be hardly meet by small molecules (ion recognition achieved through the formation of organometallic complexes\textsuperscript{13} being a notable exception) and usually the recognition elements are based on a macromolecular structure in which a huge number of rather weak bonds (mainly H-bonds) furnishes a large binding energy and an highly specific geometrical compatibility to the binding site. Since the elaborate organization of life requires specific molecular recognition, it is not surprising that most of the recognition elements currently used in biosensing are natural systems such as antibodies, enzymes, nucleic acids, receptors; or are molecules of natural origin (polypeptide and RNA based aptamers). One of the legacy of this biological origin is their usually not high stability with respect to some harsh chemical and physical treatments. Exposure to organic solvents, extreme temperature, non-physiological pH or high salt concentrations along with adsorption to surfaces are all events that can potentially destroy the native conformation of macromolecules and limit their ability to selectively bind ligands. Therefore the steps used to anchor biological recognition elements on the active surface of biosensors must be carefully chosen.

To endow an OFET sensor of selectivity capabilities, the recognition elements should be stably secured either through integration into the device structure or by chemically anchoring them on the OSC surface. In the latter case hydroxyl, carboxyl or amino groups need to be produced on the OSC surface to covalently link the recognition elements to it. One of the most popular reactions involve the activation of carboxylic acids by the N-ethyl-N′-(3-dimethylaminopropyl)-carbodiimide hydrochloride (EDC) and N–hydroxysuccinimide (NHS). Route a in Fig. 8A describes this approach as recently proposed for DNA sensing.\textsuperscript{43}

![Fig. 8](image_url)

**Fig. 8** A) Plasma Enhanced –Chemical Vapour Deposition (PE-CVD) functionalization of the organic semiconductor surface with an hydrophilic coating characterized by carboxyl groups acting as anchor sites for biomolecules covalent attachment using the EDC/NHS chemistry. PNA strands (route a) for DNA detection, and biotynilated phospholipid layers (route b) for antibody well-oriented deposition, were anchored using this strategy. B) Functionalization of the organic semiconductor surface with gold nanoparticles used for thiolated biomolecules immobilization.

In this case, the OSC surface is coated by a -COOH rich layer deposited by plasma enhanced chemical vapor deposition (PE-CVD) then the N-terminus of peptide nucleic acids is conjugated to these carboxyls using EDC/NHS chemistry. The hybridization with complementary DNA strands leads to a measurable response. Such a strategy could be extended to proteins such as antibodies or enzymes but in such a case complications are foreseen in the presence of residues bearing primary amine group (e.g. lysine). In such a case crosslinks with the OSC surface could take place not only at the N-terminus end of the polypeptide chain but also at the positions of lysine residues with unpredictable impact on the protein functionality. In addition, controlled attachment of different recognition elements is difficult to achieve as well as the anchoring of membrane proteins.

Very recently, two strategies have been proposed that overcome these limitations by forming sensing platforms that permit the modular addition of different recognition elements. The first strategy exploits the physical chemistry of phospholipids (PL), amphiphilic molecules that are the main components of biological membranes. PL in water spontaneously self-assemble forming bilayers that under suitable conditions close themselves forming spherical PL shells known as vesicles. PLs bearing many different chemical functionalities are commercially
available so that vesicles of desired composition can easily be prepared and, if required, membrane proteins can be embedded into their bilayers. This procedure\(^4\) (route b in Fig. 8A) starts again from the OSC coated by –COOH groups through PE-CVD and the EDC/NHS chemistry is here used to stably anchor vesicles containing NH\(_2\)-functionalized phospholipids. The vesicles contain also PL bearing functional groups that can be used for subsequent coupling reactions or used directly as recognition elements (represented by blue triangles in the cartoon). Eventually, the anchored vesicles spontaneously fuse, leading to the formation of a PL bilayer stably grafted at the OSC surface. Already this stage represents a surface that can be easily functionalized exploiting the chemical groups linked to the PL. Numerous lipids are available for the attachment of proteins to the bilayer surface through amide, disulfide, thioether covalent conjugation or by means of biotin/streptavidin binding. In the original paper, PLs linked to biotin where used and the OFET was successfully able to sense streptavidin concentration down to 10 nM. Moreover, the membrane bound streptavidin has still biotin-binding sites available so that it is conceivable to use it to anchor biotinylated molecules such as antibodies.

An alternative approach is based on the thiol/gold chemistry. The procedure schematized in Fig. 8B is the following. A layer of micelles formed by the poly(styrene-b-4-vinlypryidine) block-copolymer and containing in the pyridine core HAuCl\(_4\) is spun on the OSC surface. The micelles close-pack themselves at fixed center-to-center distance. Exposure to oxygen plasma leads to the total removal of the block-copolymer and the simultaneous reduction of auric ions to metallic gold leading to an array of uniformly spaced gold nanoparticles on the OSC surface. This platform can then be easily functionalized by using thiol bearing molecules, from thiolated DNA oligomers that binds Hg\(^{2+}\) or trombin. The availability of thiolated chemicals allows indeed for the incorporation of a broad range of molecules onto the surface of the sensor.\(^5\)

Finally very recently innovative OFET architectures have been propose in which the biological recognition layer is integrated in the device by sandwiching it between the dielectric and the OSC (see next section for details). In such a case the biological recognition molecules are deposited on the dielectric surface (SiO\(_2\)) by simple spin coating or by the sequential electrostatic self-assembly of alternating layers of water soluble positively and negatively charged polyelectrolytes (a procedure called layer-by-layer adsorption). Then the film of OSC is placed on the top of the biological layer by spin-coating from organic solvent.

**OFET biosensors**

In the biosensor equivalent of an ISFET the bio-recognition elements, such as enzymes\(^6\) but also antibodies/antigens, DNA and whole cells, are either deposited on the metallic gate (as depicted in Fig. 9a) or interfaced directly to the dielectric.
MOSFET leading to a measurable $V_T$ shift. Example of this approach can be traced back to the earlier days of FET sensors and involve a MOSFET device. More generally the interaction between the analyte and the recognition element can change the gate electrochemical potential. An example is reported in Fig. 9b where a standard MOSFET is a sensor that has a redox active gate contact - Ospolyvinylpyridine (Os-PVP) containing the enzyme horseradish peroxidase (HRP) – that exhibits a high sensitivity to $\text{H}_2\text{O}_2$. The basic principle of the sensor is to measure hydrogen peroxide concentration by measuring the change in the work function of the electroactive gate of the FET due to its redox reaction with $\text{H}_2\text{O}_2$. A constant current potentiometric mode is used to improve the sensitivity of the sensor. In such ISFETs configurations however, no direct interfacing between the layer where the bio-chemical reaction takes place and the electronic channel is foreseen. Moreover, the detection is generally limited to electro-active or charged species. To overcome this limitation a labeling step is often required; besides a reference electrode is needed as for other electrochemical detection system.

Switching from MOSFETs to OFETs, the ISFET-like configuration sees a gating of the OFET that is produced by directly interfacing the OSC with an electrolyte solution. Two classes of devices are originated: the electrochemical transistors (ECTs) and the electrolyte gated FET (EGOFETs). An example from the production of the Malliaras’ group is used to briefly describe the ECTs sensing mechanism. An ionic liquid is used as electrolyte to disperse the glucose oxidase enzyme and a ferrocene redox mediator. The redox-reaction between the glucose and the enzyme (GOx) takes place and cycles back with the help of the Fc/ferricenium ion (Fc+) couple, which shuttles electrons to the gate electrode. At the same time, cations from the solution enter the OSC and dope or dedope it affecting in this way the $I_{DS}$ current to a degree that depends on glucose concentration. The transduction mechanism is therefore connected to the doping of the OSC and it is usually addressed as electrochemical in nature. Due to the amplification inherent in the transistor concentrations down to the 100 nM of glucose could be detected. Also for this configuration an electro-active analyte is often required, but they do operate at very low voltages.

Another interesting approach is implemented in the EGOFET sensors where an electrolyte solution directly produces the gating for the OFET (Fig. 10a).

In EGOFETs the dielectric gating is achieved through the formation of a Debye-Helmholtz double layer at the interface between the electrolyte solution and the OSC layer as well as between the electrolyte and gate contact. In fact this double layer holds a very high capacitance (ca. $10 \ \mu\text{F cm}^{-2}$) and the device can be operated by ranging $V_{GS}$ and $V_{DS}$ in the sub-volt regime. For bio-sensing purposes a bio-recognition element should be anchored to the OSC, allowing to directly interface the bio-layer to the OSC. Such an architecture indeed holds the problem of directly grafting recognition bio-elements, hydrophilic in nature, to the OSC notably highly.
hydrophobic. In a first example of EGOFET the grafting of the recognition element involved the whole bulk of the OSC rather than the sole active surface. The sensing showed DNA determination in the 0.1 μM concentration range in pure water while no signal could be detected in saline solution.\textsuperscript{40} High ionic concentration in fact ended up doping the OSC, which is not desirable in an EGOFET configuration. A better solution turned out to be the bio-functionalization of either one of the two available Debye-Helmholtz interfaces: gate/electrolyte and electrolyte/OSC. The example reported in Fig. 10b, involves the bio-functionalization of the gate electrode with a self-assembled monolayer of a boronic acid that holds high chemical affinity towards molecules with geminal diol groups such as dopamine.\textsuperscript{4} Upon binding of dopamine a negatively charged boronic ester is formed whose charge is counterbalanced by the dopamine amine group. As this electrical dipole is formed the potential drop at the gate-liquid interface increases thus causing a current decrease as higher gate voltages are needed to compensate. In this case, being a dipole involved rather than a net charge, the sensing effect is on the gating capacitance, rather than on the electrochemical potential. As small capacitance changes upon formation of the complex can dominate over the in-series large capacitance of the electrolyte, detection of analyte in the pM regime are feasible, although no assessment of the LOD and the LOQ was provided. A second possibility involves the OSC/electrolyte interface that can be bio-functionalized by anchoring (Fig. 10c) a phospholipid bilayer containing the recognition elements, to the OSC according to route (b) of Fig. 8A. In this configuration, a bilayer of zwitterionic PL can be used to both immobilizing the biotin recognition element and hindering the electrolyte ions diffusion into the OSC. This is confirmed by the I-V characteristics (Fig. 10d) exhibiting very low hysteresis upon forward and backward potential scan along with a low gate leakage current $I_{DS}$. The sensing mechanism involves an $I_{DS}$ current increase generated this time by the extra gating produced by the streptavidin recognition, as this protein is negatively charged at the operating pH. This time an overall electrochemical potential increase is seen as proven by the $V_T$ shift towards positive gate potentials. The sensing is proven to be selective as a number of negative control experiments involving a PL layer with no immobilized biotin as well as bare P3HT OSC, gave the expected zero response. The LOD and the LOQ, taken from the calibration curve reported in Fig. 3, are down to the nM level and have been measured in the presence of a physiological relevant electrolyte concentrations, namely at an ionic strength comparable to that of blood.\textsuperscript{44} Although EGOFET is an interesting sensing structure, still the bio-recognition event takes place either on the gate contact surface or at the bio-layer interface opposite to that with the OSC electronic channel, with the presence of the PL layer further hampering the direct coupling between a bio-recognition event and the electronic channel. Last but not least, reliability problems are connected with the gate contact positioning and the need of a reference electrode has not been definitively ruled out. On the other hand, this configuration allows, for a given interface, a direct control of the potential at the bio-layer/OSC interface.

Another interesting ISFET-like OFET sensing approach that does not need a reference electrode, is the so called Charge Modulated (CM) OFET. In this extended gate OFET, the gate sensing area and the channel region are physically separated and DNA label free detection has been reported in the sub nM range.\textsuperscript{45} However, also in this case the bio-recognition is limited to charged species and there is, by definition, no direct coupling of bio-recognition and FET channel. This is however a
good experimental tool to measure the sole capacitive effects in a given bio-organic interface.

Indeed, so far the detection with a solid state device has been pushed towards its limits with transistors comprising a single nanostructured semiconducting element. Nanostructured channel materials such as a single silicon nanowire or a carbon nanotube bearing a recognition element on the surface, allow both the close-coupling between the bio-recognition event and the field-induced transport along with a conveniently low interaction cross-section; both concur to achieve extremely sensitive electronic responses allowing the detection of a single molecule. The bio-recognition element is anchored to the nanostructured semiconductor surface and electrolyte gating is mostly adopted, although back-gating through oxide dielectrics is also used. As to the biotin-streptavidin assay is concerned the lowest detection was achieved with a biotinylated Si nanowire capable to sense down to 25 pM. The main drawbacks of these achievements, otherwise challenging and fascinating, are the technological issues inherent to a nano-device reliable fabrication that impact on the response repeatability, limiting the overall quality of the data set in the systematic investigations needed to shed light on bio-electronic transduction mechanisms. High-cost production and the difficult scalability are also issues. Conversely, OFETs can be fabricated by low-cost, large-area printing procedure. Recently also back-gated OFETs have been proposed for highly performing electronic bio-sensing. Indeed this approach produces a label-free response and there is no need for a reference electrode. At first the bio-recognition element was deposited/grafted on top of the OSC layer. This structure, known as the Bi-Layer (BL)OFET, is reported in Fig. 11.

![Fig. 11](image-url) (a) Bottom gate-Top contact OFET biosensor having a Bi-Layer structure in which the bio-recognition layer is deposited on the organic semiconductor surface. (b) Normalized $I_{DS}$ current changes upon thrombin exposure of a OFET decorated with gold nanoparticle (AuNP) binding sites for thrombin protein DNA binding aptamers. Reprinted from reference 45, Copyright© 2013 American Chemical Society, reproduced with permission from American Chemical Society.

One of the first papers dealing with this structure involved the deposition of amino acid or glucosidic units on the OSC to endow the OFET with chiral-recognition capability. Indeed, electronic chiral differential detection was achieved for citronellol and carvone enantiomers at the ppm concentration level, pushing the limit of solid-state chiral determination down by three orders of magnitude. Fig. 11b shows the response of a water-stable OFET whose S and D electrodes are protected with a thin layer of SiOx and the OSC is decorated with an ordered array of AuNPs as described in Fig. 8B. Thrombin-specific aptamers are attached to the AuNPs via Au-S linkage, and the device surface is blocked against nonspecific protein adsorption with bovine serum albumin (BSA). Upon exposure to the target protein, the aptamers bind thrombin. The current is seen to scale linearly with the logarithm of the concentration as expected in FET-type sensors and negative control was achieved when no capturing molecule was immobilized on the OSC surface. The selective detection of thrombin was successfully achieved down to 100 pM. The ionic strength and pH of the buffer as well as the density of the receptor sites affected the detection profile. Investigation of the effect of the buffer's ionic strength on detection revealed that, while charge screening prohibits charge-based OFET thrombin detection at high (140 mM) ionic strengths, this limitation may be overcome by a suitable reduction in ionic strength. In general, increasing the overall
net charge of the protein analyte resulted in increased sensitivity.

The response of a bottom gate OFETs bearing sulfate binding protein immobilized on top of the semiconductor has been also proposed. In this case, the immobilization was accomplished on the surface of an extra insulating layer also deposited on the OSC. The insulating layer consists of maleimide functionalized polystyrene (PSMI), capable to anchor the protein recognition element. The device was exposed just to 1mM Na₂SO₄ solution and measured under dry conditions. An effective charge per protein of -1.7q was estimated for the threshold shift, being quite close to the -2q expected value as each protein should capture one SO⁻₂⁵.⁵⁰

Bottom gate OFET functionalized with PNA as described in route a of Fig. 8A successfully lead to DNA detection at the low nM level by covalently immobilising PNA probes on the OSC surface.⁵¹ Repeatability of the sensors was investigated for two concentrations (100 and 200 nM). Similarly to the previous approach, immobilization of BSA has been realized for the in situ detection of anti-BSA.⁵²

Different concentrations were detected ranging from 10 nM to 2 μM.

The BLOFET structure clearly produced some very interesting results particularly when implemented with the gold nanoparticles arrays that, while interacting with the analyte, involve charge modifications that reflect on the OSC 2D transport. The sensing mechanisms in BLOFETs, that do not involve charged species, are similar to those already discussed for the OFET chemical sensors although in BLOFET the analyte direct impact on the 2D transport layer is mediated by its selective interaction with the external layer bearing the bio-recognition element. Basically for not-charged species the external layer acts like a filter retaining aliquots of the analyte. The stronger the interaction the least analyte percolated down to the interface. To achieve a more closer contact between the recognition event and the OSC 2D layer in a BLOFET configuration, an OSC as thin as the 2D transport layer can be used. This approach was pursued by physically adsorbing DNA molecules on the surface of an ultra-thin pentacene films.⁵³ Measurements of the electrical performance were carried out in the dry state. The device was exposed to DNA solutions exhibiting a sensitivity of 0.2 μM. Such an approach requires a strict control over the interfacial properties to assure good reproducibility, bringing us back to the stability and reproducibility issues already discussed for the nano-structured FET sensors.

Lately, a novel structure was conceived with the aim of creating a direct interface between the OSC and the capturing molecules. This biosensor comprises an OFET device were the bio-layer is deposited underneath the OSC, resulting in the Functional Biological Interlayer (FBI)OFET⁵⁴ depicted in Fig. 12a.

**Fig. 12** a) Bottom gate-Top contact OFET biosensor having a FBI structure in which the bio-recognition layer is deposited directly at the dielectric and organic semiconductor interface. b) FBI-OFET embedding a streptavidin bio-recognition layer along with typical I-V characteristic curves in panel c)

Clearly in such a device an intimate contact is created between the region where the bio-recognition takes place and the OCS FET channel. It foresees also an electronic transduction, though difficult to achieve as the FBI-OFET functions on the basis of a counterintuitive approach involving a FET electronic channel set to work on top of a biological deposit. By knowing how critically the FET transport depends on the dielectric/OSC interface quality and seeing how rough a protein deposit can be, a successful FET transport was evaluated as highly unlikely. In fact, the results
reported in Fig. 12c furnish compelling evidence that this is not the case. Fig. 12b shows the FBI-OFET fabricated on a standard rigid Si-SiO₂ substrate, (SiO₂ being 300 nm thick) embedding a streptavidin (SA) bio-layer residing underneath a poly-hexylthiophene (P3HT) thin-film (SA spin-coated from water and P3HT from chloroform). In Fig. 12c the I-V characteristic curves are measured on a FBI-OFET, showing that FET transport occurs with figures of merit that, though affected by the integration of the recognition element, are still quite good (μ from 4 to 2 10⁻³ cm²/Vs, V_T from 5 to 20 V, on/off ratio from 10⁴ to 10⁵). Applied biases would have been lower than 5 V if a high-k thinner dielectric would have been used. An improvement of these figures is foreseen by using a higher mobility OSC (Tips-pentacene for instance) and/or by using different deposition procedures (Langmuir Blodgett, L-B, spray-coatings).

The possibility to have a FET transport on top of a bio-deposit opens the door to the direct electronic probing of bio-recognition events. It is known that SA has a selective and almost irreversible interaction with biotin, leading to the formation of a very stable complex (dissociation constant of fM). In this process, SA undergoes a conformational change causing the characteristic string loops to close on the incorporated biotin. Biotin binding to SA is depicted in Fig. 13a (biotins are the grey triangles, the SA tetrameric protein is sketched by the four black circles).

**Fig. 13** a) Schematic structure of streptavidin evidencing the four biotin binding sites and their conformational change after biotin interaction. b) Detailed structure of a streptavidin recognition site after the biotin binding. Reprinted from reference 55, Copyright© 2000 The Protein Society, reproduced with permission from John Wiley & Sons, Inc.

Fig. 13b shows a detail of one of the SA lobes, showing how the red loop turns into the black one as the biotin-SA complex is formed. As in the FBI-OFET the complex is formed just underneath the OSC a very sensitive response is expected.

The results of the SA FBI-OFET exposed to biotin solutions of different concentrations (from pM to nM) are reported in Fig. 14a as the relevant I-V transfer characteristics.

**Fig. 14** a) Typical I_DS-V_G curves obtained for a streptavidin FBI-OFET exposed to pure water and biotin solutions at different concentrations. b) Response of a spin-coated streptavidin FBI-OFET to different biotin concentrations. Each data point is the ΔI/I₀ mean value over three replicates measured on different OFET devices. Error bars are taken as the relative standard deviations. The response to different biotin concentrations for FBI-OFETs embedding other capturing layers used as negative controls is also reported. Triangles: saturated streptavidin-biotin complexes FBI-OFET; squares: P3HT-OFET; diamonds: bovine serum albumin FBI-OFET.

Here a systematic and scalable current decrease is observed as the device is exposed to different biotin concentrations, showing that the response appears to be directly connected with the complex formation. The relevant dose curve, reporting the relative current decrease is shown in Fig. 14b. For both panels, error bars, as standard deviations over three replicates on different SA FBI-OFET, show how the current variation is in fact significant even at the lowest concentration (50 pM) this being one of the lowest ever measured, most probably because a direct coupling with the electronic transport is created. Important to outline is that the response is not likely connected to a net charge variation effect. Indeed, extremely interesting would be to understand if this response is related to the SA loop movement (conformational change) occurring underneath the OSC and possibly affecting the polymer
π–conjugation or the local charge. The other data points present in Fig. 14b are relevant to sets of negative control experiments that provide a zero response assessing the selectivity of the streptavidin/biotin interaction in the FBI-OFET assay proposed. Also error bars are within few percent while the LOD is 50 pM and the LOQ is 100 pM. The quantification of small molecules is a rather demanding task and, in the case of biotin, nM concentration levels have been detected at most, even with extremely sensitive non electronic determinations such as an electrochemical and a label needing fluorescent assay, both carried out in solution. The label-free FBI-OFET approach allows reaching detection levels that are comparable to those so far achieved by much more performing nanostructured sensors. Also relevant is that the FBI-OFET determination does not need a reference electrode and can be performed also in the case of neutral species. One drawback is the necessity for the analyte to percolate through the OCS layer.

Conclusions

Organic field-effect transistor are presented as label-free, sensitive and selective electronic sensors. This review provides the also the most relevant learning points, from the analytical sensor figures of merit to the salient details of the OFET transport. Moreover, details on the bio-functionalization of a OFET device surface are presented. All the major sensor device configurations are introduced highlighting the most significant achievements along with the limitations. The sensing mechanisms are discussed and important issues such as low-voltage operation as well as the need for a reference electrode or to ability to sense charged or neutral bio-molecules are presented for the different configurations. The assessment of the analytical figures of merit is also highlighted, stressing how the validation of an analytical method is an essential step to prove its capability to provide reliable qualitative or quantitative data. This applies also and more compellingly to a novel technology such as electronic biosensing is.

This reviews highlights also how the driving force towards the use of OFET as biosensors is to combine the electronic output signal and the high sensing performance level with low-cost fabrication to develop disposable electronic sensing systems that would turn ideal for POC testing and how electronic biosensing on a disposable strip-test is considered the next paradigm shift in diagnostics.

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Notes and References

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54 D. Angione et al. PNAS 2012, 109, 6429-6434.